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Inclosure	Material:
Ceramic	
Overall L	ength:
1.145 inch	nes
Terminal	Length:
0.381 inch	nes
Overall H	eight:
0.165 inch	nes
Overall W	/idth:
0.400 inch	nes
End Appl	ication:
6625-01-2	230-7325 recorder, tape
Internal C	Configuration:
Junction d	contact
Joint Elec	ctronic Device Engineering Council/jedec/case Outline Designation:
To-220ab	
Mounting	Method:
Terminal	
Semicon	ductor Material:
Silicon	
Voltage R	Rating In Volts Per Characteristic:
60.0 brea	kdown voltage, collector-to-emitter, base open
Current R	Rating Per Characteristic:
3.00 ampe	eres source cutoff current
Power Ra	ating Per Characteristic:
25.0 watts	s small-signal input power, common-collector absolute
Maximum	Operating Tempurature Per Measurement Point:
150.0 deg	rees celsius junction
Special F	eatures:
Junction p	pattern arrangement: pnp
Terminal	Type And Quantity:
3 pin	
Shelf Life	r:
N/a	
Unit Of M	leasure:
Demilitari	ization:
No	
Fiig:	